

General Description

The WSR70P10 is the highest performance trench P-Ch MOSFET with extreme high cell density , which provide excellent $R_{\mbox{\scriptsize DSON}}$ and gate charge for most of the small power switching and load switch applications.

The WSR70P10 meet the RoHS and Green Product requirement with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent Cdv/dt effect decline
- Green Device Available

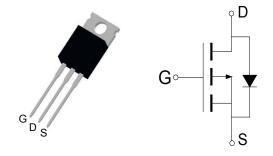
Product Summery

BV _{DSS}	R _{DSON}	I _D
-100V	18mΩ	-70A

Applications

Inverters

TO-220AB Pin Configuration



Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit		
Common R	atings (T _C =25°C Unless Otherwise Noted)		1		
V_{DSS}	Drain-Source Voltage				
V_{GSS}	Gate-Source Voltage	±25	V		
TJ	Maximum Junction Temperature	175	°C		
T _{STG}	Storage Temperature Range		-55 to 175	°C	
I _S	Diode Continuous Forward Current	T _C =25°C	-70	Α	
Mounted or	Large Heat Sink				
I_{DP}	300μs Pulse Drain Current Tested	T _C =25°C	-240	А	
$I_D^{\textcircled{2}}$	Continuous Drain Current(V _{GS} =-10V)	T _C =25°C	-70		
		T _C =100°C	-45	Α	
P_D	Maximum Dayor Dissination	T _C =25°C	190	W	
	Maximum Power Dissipation	T _C =100°C	95		
$R_{ heta JC}$	Thermal Resistance-Junction to Case	0.8	°C/W		
$R_{ heta JA}$	Thermal Resistance-Junction to Ambient	62.5	°C/W		
Drain-Sourc	ce Avalanche Ratings				
E _{AS}	Avalanche Energy, Single Pulsed		400	mJ	



Electrical Characteristics (T_C=25°C Unless Otherwise Noted)

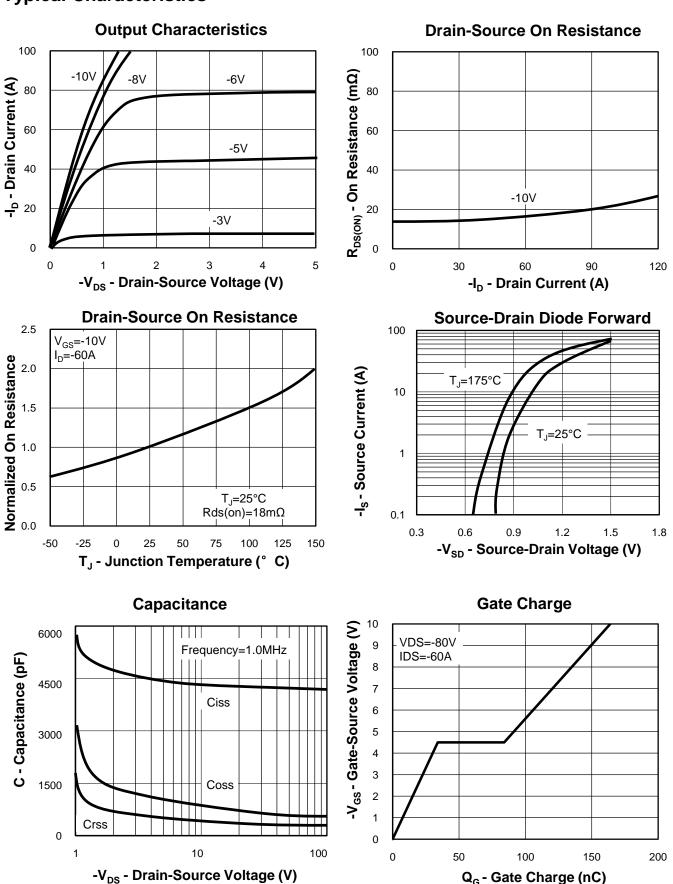
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Static Cha	racteristics		•			
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _{DS} =-250μA	-100			V
	Zero Gate Voltage Drain Current	V _{DS} =-100V, V _{GS} =0V			-1	μA
I _{DSS}		T _J =125°C			-30	
V _{GS(th)}	Gate Threshold Voltage	$V_{DS}=V_{GS}$, $I_{DS}=-250\mu A$	-2		-4	V
I _{GSS}	Gate Leakage Current	V_{GS} =±25V, V_{DS} =0V			±100	nA
R _{DS(ON)}	Drain-Source On-state Resistance	V _{GS} =-10V, I _{DS} =-60A		18	25	mΩ
Diode Cha	racteristics		•	•		
V _{SD}	Diode Forward Voltage	I _{SD} =-30A, V _{GS} =0V			-1.5	٧
trr	Reverse Recovery Time			175		ns
Qrr	Reverse Recovery Charge	IsD=-60A, dlsD/dt=100A/µs		620		nC
Dynamic C	Characteristics ^⑤					
R _G	Gate Resistance	V _{GS} =0V,V _{DS} =0V,F=1MHz		2		Ω
C _{iss}	Input Capacitance	V _{GS} =0V,		4200		pF
C _{oss}	Output Capacitance	V _{DS} =-50V, Frequency=1.0MHz		615		
C _{rss}	Reverse Transfer Capacitance			380		
t _{d(ON)}	Turn-on Delay Time	V_{DD} =-50V, I_{DS} =-60A, V_{GEN} =-10V, R_{G} =6 Ω		27		ns
t _r	Turn-on Rise Time			83		
t _{d(OFF)}	Turn-off Delay Time			145		
t _f	Turn-off Fall Time			40		
Gate Char	ge Characteristics ^⑤		•			
Q _g	Total Gate Charge			164		nC
Q _{gs}	Gate-Source Charge	V _{DS} =-80V, V _{GS} =-10V, I _{DS} =-60A		34		
Q_{gd}	Gate-Drain Charge	1 _{DS} =-00A		50		
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Notes:

- ①Pulse width limited by safe operating area.
- ②Calculated continuous current based on maximum allowable junction temperature.
- ③Limited by T_{Jmax} , I_{AS} =-40A, V_{DD} =-60V, R_{G} = 50Ω, Starting T_{J} = 25° C.
- ④Pulse test;Pulse width≤300µs, duty cycle≤2%.
- ⑤Guaranteed by design, not subject to production testing.

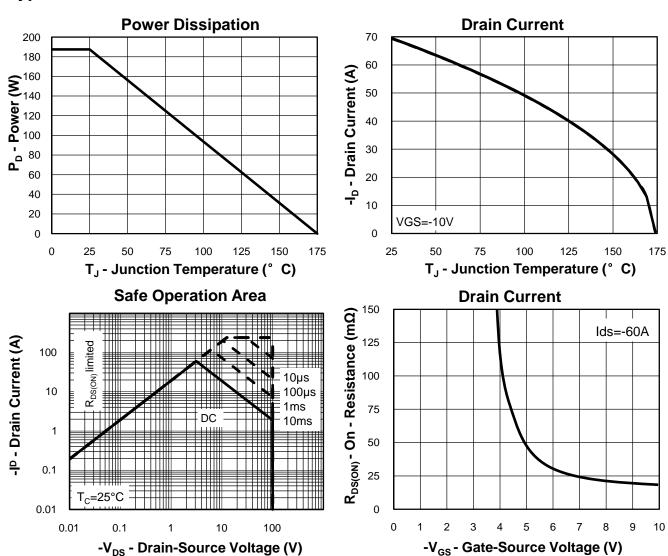


Typical Characteristics

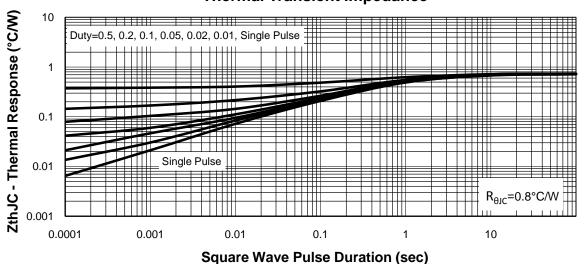




Typical Characteristics



Thermal Transient Impedance





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